

# Monolithic Function Generator

## GENERAL DESCRIPTION

The XR-2206 is a monolithic function generator integrated circuit capable of producing high quality sine, square, triangle, ramp, and pulse waveforms of high-stability and accuracy. The output waveforms can be both amplitude and frequency modulated by an external voltage. Frequency of operation can be selected externally over a range of 0.01 Hz to more than 1 MHz.

The circuit is ideally suited for communications, instrumentation, and function generator applications requiring sinusoidal tone, AM, FM, or FSK generation. It has a typical drift specification of 20 ppm/°C. The oscillator frequency can be linearly swept over a 2000:1 frequency range, with an external control voltage, having a very small affect on distortion.

## FEATURES

Low-Sine Wave Distortion	.5%, Typical
Excellent Temperature Stability	20 ppm/°C, Typical
Wide Sweep Range	2000:1, Typical
Low-Supply Sensitivity	0.01%V, Typical
Linear Amplitude Modulation	
TTL Compatible FSK Controls	
Wide Supply Range	10V to 26V
Adjustable Duty Cycle	1% to 99%

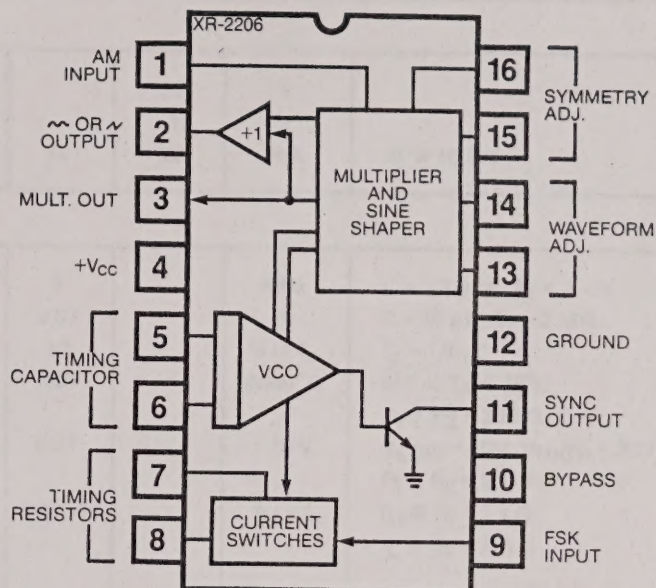
## APPLICATIONS

Waveform Generation  
Sweep Generation  
AM/FM Generation  
V/F Conversion  
FSK Generation  
Phase-Locked Loops (VCO)

## ABSOLUTE MAXIMUM RATINGS

Power Supply	26V
Power Dissipation	750 mW
Derate Above 25°C	5 mW/°C
Total Timing Current	6 mA
Storage Temperature	-65°C to +150°C

## FUNCTIONAL BLOCK DIAGRAM



## ORDERING INFORMATION

Part Number	Package	Operating Temperature
XR-2206M	Ceramic	-55°C to +125°C
XR-2206N	Ceramic	0°C to +70°C
XR-2206P	Plastic	0°C to +70°C
XR-2206CN	Ceramic	0°C to +70°C
XR-2206CP	Plastic	0°C to +70°C

## SYSTEM DESCRIPTION

The XR-2206 is comprised of four functional blocks; a voltage-controlled oscillator (VCO), an analog multiplier and sine-shaper; a unity gain buffer amplifier; and a set of current switches.

The VCO actually produces an output frequency proportional to an input current, which is produced by a resistor from the timing terminals to ground. The current switches route one of the timing pins current to the VCO controlled by an FSK input pin, to produce an output frequency. With two timing pins, two discrete output frequencies can be independently produced for FSK Generation Applications.







## ELECTRICAL CHARACTERISTICS

**Test Conditions:** Test Circuit of Figure 1,  $V^+ = 12V$ ,  $T_A = 25^\circ$ ,  $C = 0.01 \mu F$ ,  $R_1 = 100 k\Omega$ ,  $R_2 = 10 k\Omega$ ,  $R_3 = 25 k\Omega$  unless otherwise specified.  $S_1$  open for triangle, closed for sine wave.

PARAMETER	XR-2206M			XR-2206C			UNIT	CONDITIONS
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.		
GENERAL CHARACTERISTICS								
Single Supply Voltage	10		26	10		26	V	$R_1 \geq 10\text{ k}\Omega$
Split-Supply Voltage	$\pm 5$		$\pm 13$	$\pm 5$		$\pm 13$	V	
Supply Current		12	17		14	20	mA	
OSCILLATOR SECTION								
Max. Operating Frequency	0.5	1		0.5	1		MHz	$C = 1000\text{ pF}$ , $R_1 = 1\text{ k}\Omega$
Lowest Practical Frequency		0.01			0.01		Hz	$C = 50\text{ }\mu\text{F}$ , $R_1 = 2\text{ M}\Omega$
Frequency Accuracy		$\pm 1$	$\pm 4$		$\pm 2$		% of $f_o$	$f_o = 1/R_1 C$
Temperature Stability		$\pm 10$	$\pm 50$		$\pm 20$		ppm/ $^\circ\text{C}$	$0^\circ\text{C} \leq T_A \leq 75^\circ\text{C}$ , $R_1 = R_2 = 20\text{ k}\Omega$
Supply Sensitivity		0.01	0.1		0.01		%/V	$V_{\text{LOW}} = 10\text{V}$ , $V_{\text{HIGH}} = 20\text{V}$ , $R_1 = R_2 = 20\text{ k}\Omega$
Sweep Range	1000:1	2000:1			2000:1		$f_H = f_L$	$f_H @ R_1 = 1\text{ k}\Omega$ $f_L @ R_1 = 2\text{ M}\Omega$
Sweep Linearity								
10:1 Sweep		2			2		%	$f_L = 1\text{ kHz}$ , $f_H = 10\text{ kHz}$
1000:1 Sweep		8			8		%	$f_L = 100\text{ Hz}$ , $f_H = 100\text{ kHz}$
FM Distortion		0.1			0.1		%	$\pm 10\%$ Deviation
Recommended Timing Components								
Timing Capacitor: C	0.001		100	0.001		100	$\mu\text{F}$	See Figure 4.
Timing Resistors: $R_1$ & $R_2$	1		2000	1		2000	$\text{k}\Omega$	
Triangle Sine Wave Output								See Note 1, Figure 2.
Triangle Amplitude		160			160		mV/ $\text{k}\Omega$	Figure 1, $S_1$ Open
Sine Wave Amplitude	40	60	80		60		mV/ $\text{k}\Omega$	Figure 1, $S_1$ Closed
Max. Output Swing		6			6		V <sub>p-p</sub>	
Output Impedance		600			600		$\Omega$	
Triangle Linearity		1			1		%	
Amplitude Stability		0.5			0.5		dB	For 1000:1 Sweep
Sine Wave Amplitude Stability		4800			4800		ppm/ $^\circ\text{C}$	See Note 2.
Sine Wave Distortion								
Without Adjustment		2.5			2.5		%	$R_1 = 30\text{ k}\Omega$
With Adjustment		0.4	1.0		0.5	1.5	%	See Figures 6 and 7.
Amplitude Modulation								
Input Impedance	50	100		50	100		$\text{k}\Omega$	
Modulation Range		100			100		%	
Carrier Suppression		55			55		dB	
Linearity		2			2		%	For 95% modulation
Square-Wave Output								
Amplitude		12			12		V <sub>p-p</sub>	Measured at Pin 11.
Rise Time		250			250		nsec	$C_L = 10\text{ pF}$
Fall Time		50			50		nsec	$C_L = 10\text{ pF}$
Saturation Voltage		0.2	0.4		0.2	0.6	V	$I_L = 2\text{ mA}$
Leakage Current		0.1	20		0.1	100	$\mu\text{A}$	$V_{I1} = 26\text{V}$
FSK Keying Level (Pin 9)	0.8	1.4	2.4	0.8	1.4	2.4	V	See section on circuit controls
Reference Bypass Voltage	2.9	3.1	3.3	2.5	3	3.5	V	Measured at Pin 10.

**Note 1:** Output amplitude is directly proportional to the resistance  $R_1$  from Pin 9 to  $V^+$ .





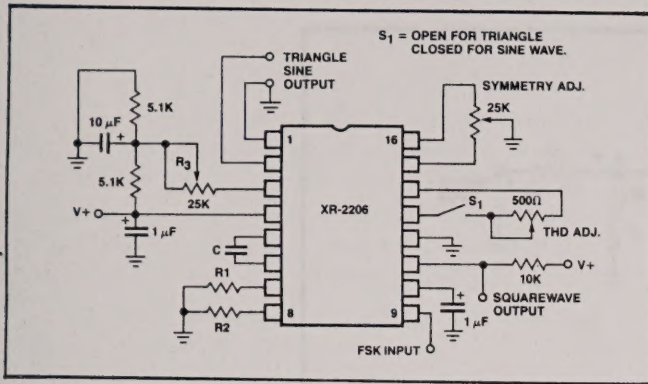


Figure 1: Basic Test Circuit.

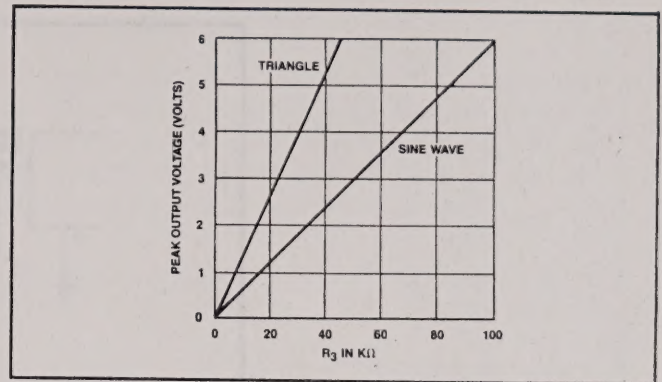


Figure 2: Output Amplitude as a Function of the Resistor,  $R_3$ , at Pin 3.

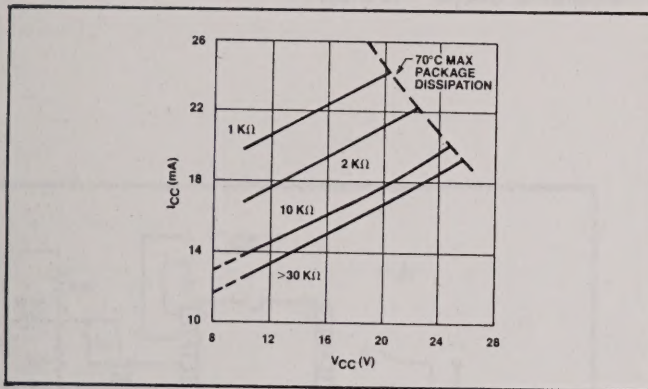


Figure 3: Supply Current versus Supply Voltage, Timing,  $R$ .

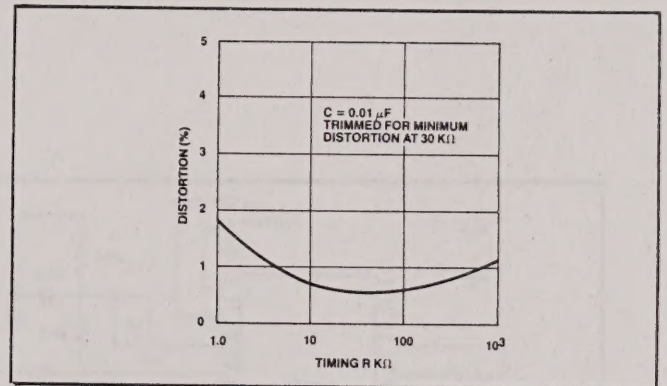


Figure 6: Trimmed Distortion versus Timing Resistor.

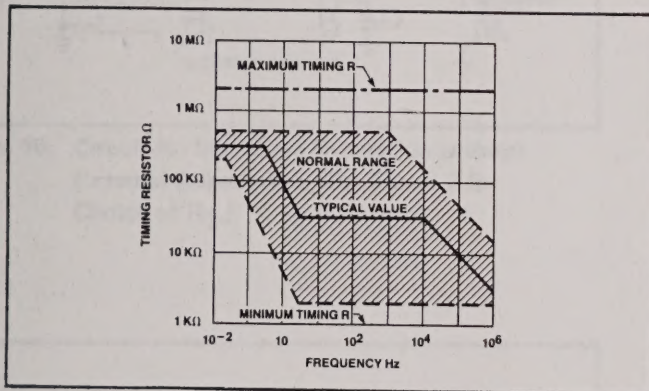


Figure 4:  $R$  versus Oscillation Frequency.

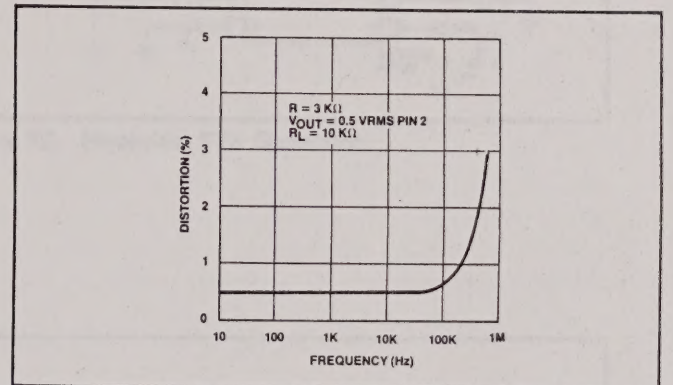


Figure 7: Sine Wave Distortion versus Operating Frequency with Timing Capacitors Varied.

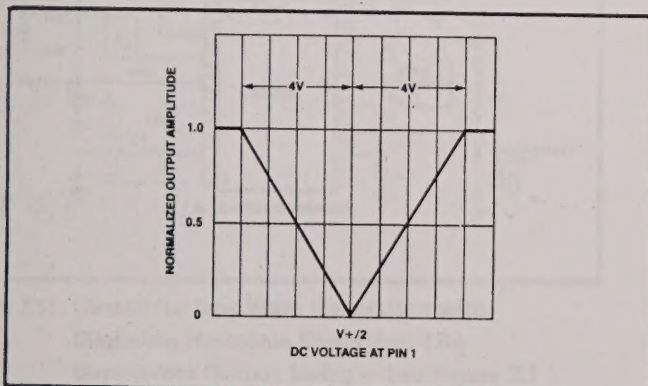


Figure 5: Normalized Output Amplitude versus DC Bias at AM Input (Pin 1).

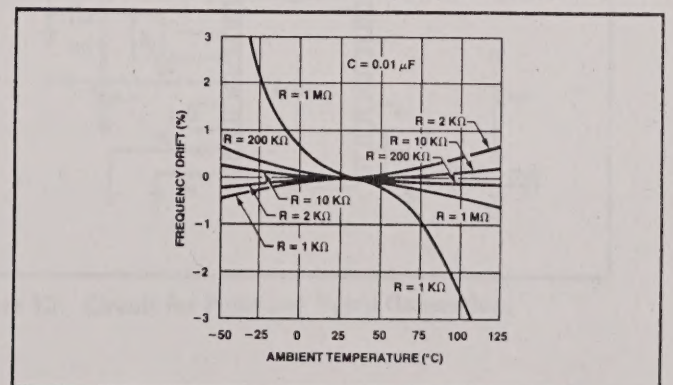


Figure 8: Frequency Drift versus Temperature.





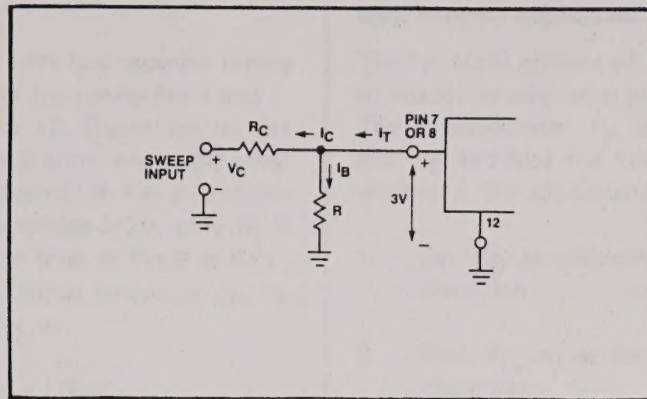


Figure 9: Circuit Connection for Frequency Sweep.

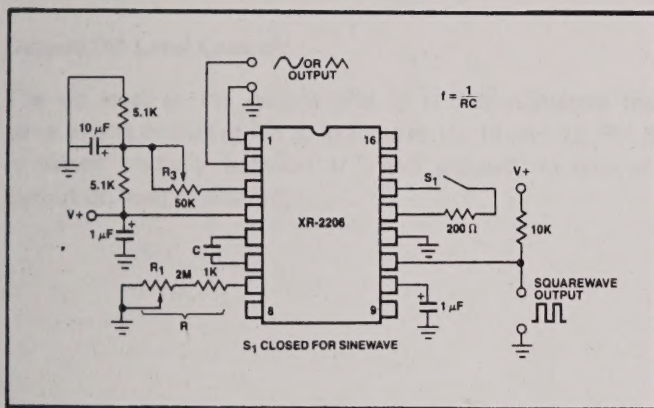


Figure 10: Circuit for Sine Wave Generation without External Adjustment. (See Figure 2 for Choice of  $R_3$ .)

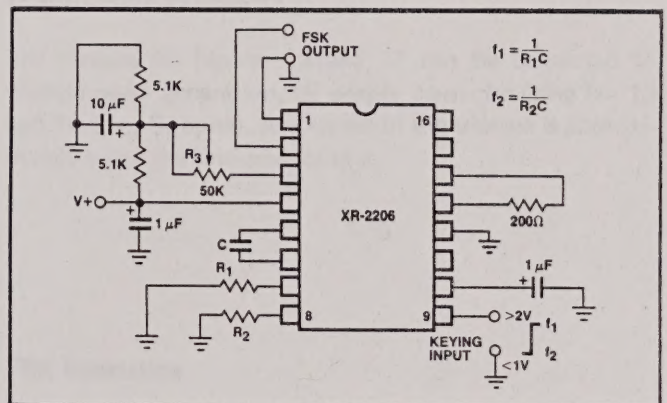


Figure 12: Sinusoidal FSK Generator.

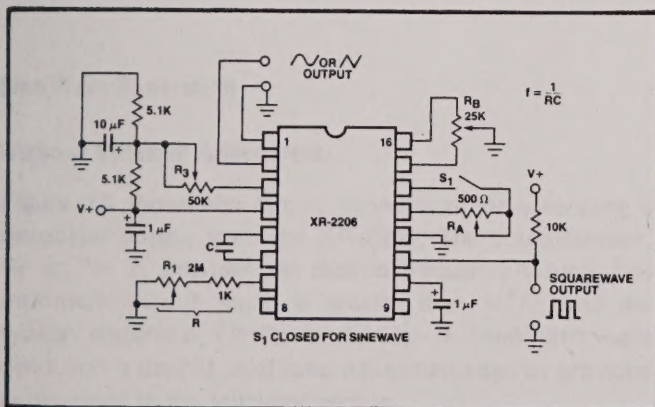


Figure 11: Circuit for Sine Wave Generation with Minimum Harmonic Distortion. ( $R_3$  Determines Output Swing — See Figure 2.)

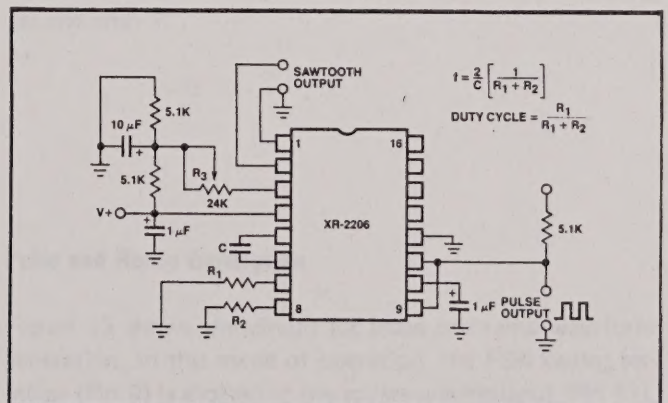


Figure 13: Circuit for Pulse and Ramp Generation.





**Frequency-Shift Keying:**

The XR-2206 can be operated with two separate timing resistors,  $R_1$  and  $R_2$ , connected to the timing Pin 7 and 8, respectively, as shown in Figure 12. Depending on the polarity of the logic signal at Pin 9, either one or the other of these timing resistors is activated. If Pin 9 is open-circuited or connected to a bias voltage  $\geq 2V$ , only  $R_1$  is activated. Similarly, if the voltage level at Pin 9 is  $\leq 1V$ , only  $R_2$  is activated. Thus, the output frequency can be keyed between two levels,  $f_1$  and  $f_2$ , as:

$$f_1 = 1/R_1C \text{ and } f_2 = 1/R_2C$$

For split-supply operation, the keying voltage at Pin 9 is referenced to  $V^-$ .

**Output DC Level Control:**

The dc level at the output (Pin 2) is approximately the same as the dc bias at Pin 3. In Figures 10, 11 and 12, Pin 3 is biased midway between  $V^+$  and ground, to give an output dc level of  $\approx V^+/2$ .

**APPLICATIONS INFORMATION****Sine Wave Generation****Without External Adjustment:**

Figure 10 shows the circuit connection for generating a sinusoidal output from the XR-2206. The potentiometer,  $R_1$  at Pin 7, provides the desired frequency tuning. The maximum output swing is greater than  $V^+/2$ , and the typical distortion (THD) is  $< 2.5\%$ . If lower sine wave distortion is desired, additional adjustments can be provided as described in the following section.

The circuit of Figure 10 can be converted to split-supply operation, simply by replacing all ground connections with  $V^-$ . For split-supply operation,  $R_3$  can be directly connected to ground.

**With External Adjustment:**

The harmonic content of sinusoidal output can be reduced to  $\approx 0.5\%$  by additional adjustments as shown in Figure 11. The potentiometer,  $R_A$ , adjusts the sine-shaping resistor, and  $R_B$  provides the fine adjustment for the waveform symmetry. The adjustment procedure is as follows:

1. Set  $R_B$  at midpoint, and adjust  $R_A$  for minimum distortion.
2. With  $R_A$  set as above, adjust  $R_B$  to further reduce distortion.

**Triangle Wave Generation**

The circuits of Figures 10 and 11 can be converted to triangle wave generation, by simply open-circuiting Pin 13 and 14 (i.e.,  $S_1$  open). Amplitude of the triangle is approximately twice the sine wave output.

**FSK Generation**

Figure 12 shows the circuit connection for sinusoidal FSK signal operation. Mark and space frequencies can be independently adjusted, by the choice of timing resistors,  $R_1$  and  $R_2$ ; the output is phase-continuous during transitions. The keying signal is applied to Pin 9. The circuit can be converted to split-supply operation by simply replacing ground with  $V^-$ .

**Pulse and Ramp Generation**

Figure 13 shows the circuit for pulse and ramp waveform generation. In this mode of operation, the FSK keying terminal (Pin 9) is shorted to the square-wave output (Pin 11), and the circuit automatically frequency-shift keys itself between two separate frequencies during the positive-going and negative-going output waveforms. The pulse width and duty cycle can be adjusted from 1% to 99%, by the choice of  $R_1$  and  $R_2$ . The values of  $R_1$  and  $R_2$  should be in the range of  $1\text{ k}\Omega$  to  $2\text{ M}\Omega$ .





## PRINCIPLES OF OPERATION

### Description of Controls

#### Frequency of Operation:

The frequency of oscillation,  $f_o$ , is determined by the external timing capacitor,  $C$ , across Pin 5 and 6, and by the timing resistor,  $R$ , connected to either Pin 7 or 8. The frequency is given as:

$$f_o = \frac{1}{RC} \text{ Hz}$$

and can be adjusted by varying either  $R$  or  $C$ . The recommended values of  $R$ , for a given frequency range, are shown in Figure 4. Temperature stability is optimum for  $4 \text{ k}\Omega < R < 200 \text{ k}\Omega$ . Recommended values of  $C$  are from  $1000 \text{ pF}$  to  $100 \text{ }\mu\text{F}$ .

#### Frequency Sweep and Modulation:

Frequency of oscillation is proportional to the total timing current,  $I_T$ , drawn from Pin 7 or 8:

$$f = \frac{320 I_T (\text{mA})}{C (\mu\text{F})} \text{ Hz}$$

Timing terminals (Pin 7 or 8) are low-impedance points, and are internally biased at  $+3\text{V}$ , with respect to Pin 12. Frequency varies linearly with  $I_T$ , over a wide range of current values, from  $1 \text{ }\mu\text{A}$  to  $3 \text{ mA}$ . The frequency can be controlled by applying a control voltage,  $V_C$ , to the activated timing pin as shown in Figure 9. The frequency of oscillation is related to  $V_C$  as:

$$f = \frac{1}{RC} \left( 1 + \frac{R}{R_C} \left( 1 - \frac{V_C}{3} \right) \right) \text{ Hz}$$

where  $V_C$  is in volts. The voltage-to-frequency conversion gain,  $K$ , is given as:

$$K = \partial f / \partial V_C = - \frac{0.32}{R_C C} \text{ Hz/V}$$

**CAUTION:** For safe operation of the circuit,  $I_T$  should be limited to  $\leq 3 \text{ mA}$ .

#### Output Amplitude:

Maximum output amplitude is inversely proportional to the external resistor,  $R_3$ , connected to Pin 3 (see Figure 2). For sine wave output, amplitude is approximately  $60 \text{ mV}$  peak per  $\text{k}\Omega$  of  $R_3$ ; for triangle, the peak amplitude is approximately  $160 \text{ mV}$  peak per  $\text{k}\Omega$  of  $R_3$ . Thus, for example,  $R_3 = 50 \text{ k}\Omega$  would produce approximately  $\pm 3\text{V}$  sinusoidal output amplitude.

#### Amplitude Modulation:

Output amplitude can be modulated by applying a dc bias and a modulating signal to Pin 1. The internal impedance at Pin 1 is approximately  $100 \text{ k}\Omega$ . Output amplitude varies linearly with the applied voltage at Pin 1, for values of dc bias at this pin, within  $\pm 4 \text{ volts}$  of  $V^+/2$  as shown in Figure 5. As this bias level approaches  $V^+/2$ , the phase of the output signal is reversed, and the amplitude goes through zero. This property is suitable for phase-shift keying and suppressed-carrier AM generation. Total dynamic range of amplitude modulation is approximately  $55 \text{ dB}$ .

**CAUTION:** AM control must be used in conjunction with a well-regulated supply, since the output amplitude now becomes a function of  $V^+$ .

### EQUIVALENT SCHEMATIC DIAGRAM

